

RJH60V1BDPP-M0

600V - 8A - IGBT Application: Inverter

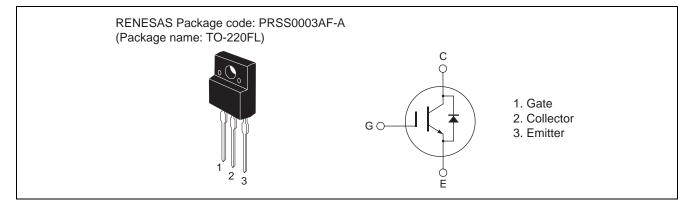
R07DS0759EJ0100 Rev.1.00 May 25, 2011

Features

- Short circuit withstand time (6 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.6 V$ typ. (at $I_C = 8 A$, $V_{GE} = 15 V$, $Ta = 25^{\circ}C$)
- Built in fast recovery diode (25 ns typ.) in one package
- Trench gate and thin wafer technology
- High speed switching

 $t_f = 110$ ns typ. (at $V_{CC} = 300$ V, $V_{GE} = 15$ V, $I_C = 8$ A, Rg = 5 Ω , inductive load)

Outline



Absolute Maximum Ratings

			$(Ta = 25^{\circ}C)$
Item	Symbol	Ratings	Unit
ge / diode reverse voltage	V _{CES} / V _R	600	V
	V _{GES}	±30	V
Tc = 25°C	Ι _C	16	А
Tc = 100°C	Ι _C	8	А
÷	ic(peak) Note1	32	А
e forward current	i _{DF}	8	А
e forward peak current	i _D (peak) Note1	32	А
		30	W
resistance (IGBT)	θj-c ^{Note2}	4.1	°C/ W
resistance (Diode)	θj-cd ^{Note2}	2.5	°C/ W
	Tj	150	°C
	Tstg	-55 to +150	°C
	ge / diode reverse voltage $Tc = 25^{\circ}C$ $Tc = 100^{\circ}C$ e forward current e forward peak current resistance (IGBT)	$ \begin{array}{c c} ge \ / \ diode \ reverse \ voltage & V_{CES} \ / \ V_R \\ \hline V_{GES} \\ \hline Tc = 25^\circ C & I_C \\ \hline Tc = 100^\circ C & I_C \\ \hline Tc = 100^\circ C & I_C \\ \hline e \ forward \ current & i_{DF} \\ \hline e \ forward \ peak \ current & i_D(peak)^{Note1} \\ \hline P_C \ ^{Note2} \\ \hline resistance \ (IGBT) & \thetaj \ cd \ ^{Note2} \\ \hline Tj \\ \hline \end{array} $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $

Notes: 1. PW \leq 10 $\mu s,\,duty\,cycle \leq$ 1%

2. Value at Tc = 25°C



Electrical Characteristics

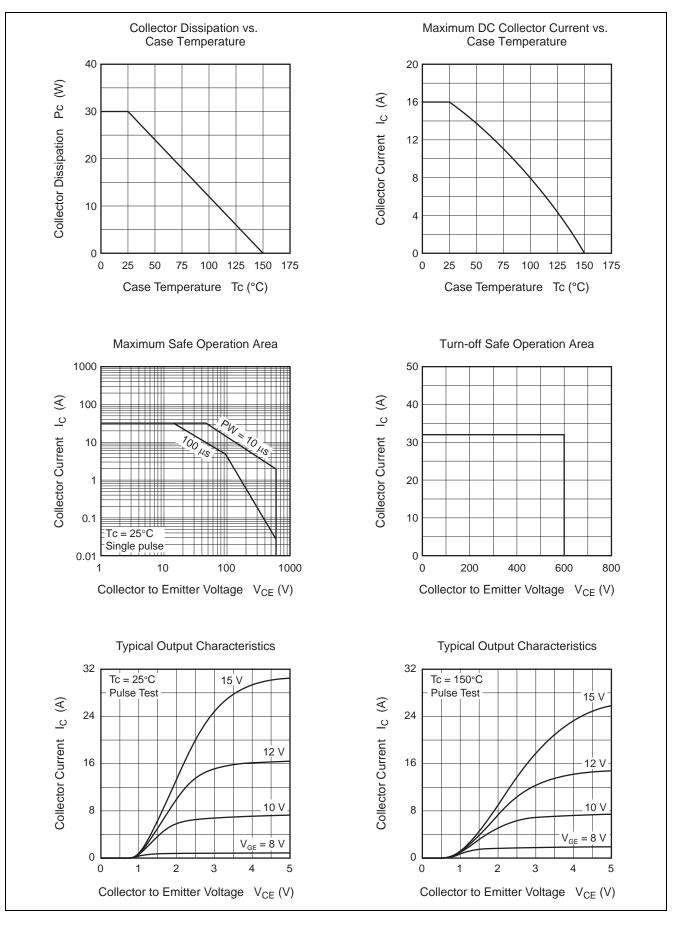
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Collector to emitter breakdown voltage	$V_{(BR)CES}$	600	—	_	V	$I_{C} = 10 \ \mu A, \ V_{GE} = 0$
Zero gate voltage collector current / Diode reverse current	I_{CES}/I_{R}	_	—	5	μΑ	$V_{CE} = 600 \text{ V}, \text{ V}_{GE} = 0$
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, \text{ V}_{CE} = 0$
Gate to emitter cutoff voltage	V _{GE(off)}	5.5	_	7.5	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.6	2.2	V	$I_{C} = 8 \text{ A}, V_{GE} = 15 \text{ V}^{Note3}$
, i i i i i i i i i i i i i i i i i i i	V _{CE(sat)}	_	2.2	_	V	I_{C} =16 A, V_{GE} = 15 V ^{Note3}
Input capacitance	Cies	_	300	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	27	_	pF	V _{GE} = 0 f = 1 MHz
Reverse transfer capacitance	Cres	_	12		pF	
Total gate charge	Qg	_	19		nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 8 A
Gate to emitter charge	Qge	_	3.5	_	nC	
Gate to collector charge	Qgc	_	11	—	nC	
Turn-on delay time	t _{d(on)}	_	30	—	ns	$V_{CC} = 300 V$ $V_{GE} = 15 V$ $I_{C} = 8 A$ $Rg = 5 \Omega$ (Inductive load)
Rise time	tr	_	12	—	ns	
Turn-off delay time	t _{d(off)}	_	55	—	ns	
Fall time	t _f	_	110	—	ns	
Turn-on energy	Eon		0.017		mJ	
Turn-off energy	E _{off}		0.11		mJ	
Total switching energy	E _{total}		0.13		mJ	
Short circuit withstand time	t _{sc}	3	6	—	μs	$\begin{array}{l} Tc = 100 \ ^{\circ}C \\ V_{GE} \ \leq \ 360 \ V, \ V_{GE} = 15 \ V \end{array}$

FRD Forward voltage	VF		2.5	_	V	I _F = 8 A ^{Note3}
FRD reverse recovery time	trr	_	25	—	ns	I _F = 8 A
FRD reverse recovery charge	Qrr	_	0.01	—	μC	di _F /dt = 100 A/µs
FRD peak reverse recovery current	Irr	_	1.0	—	Α	

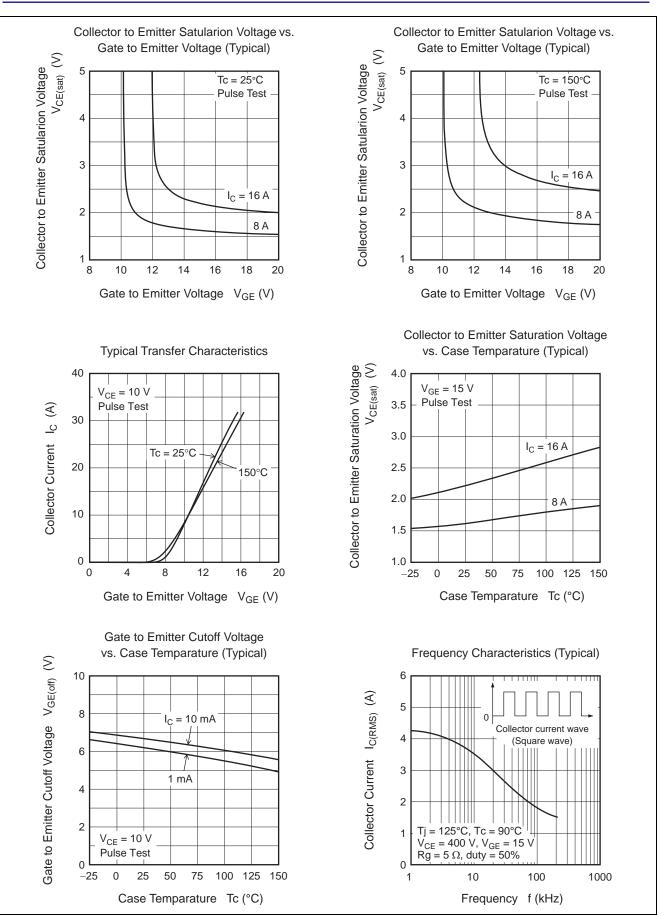
Notes: 3. Pulse test.

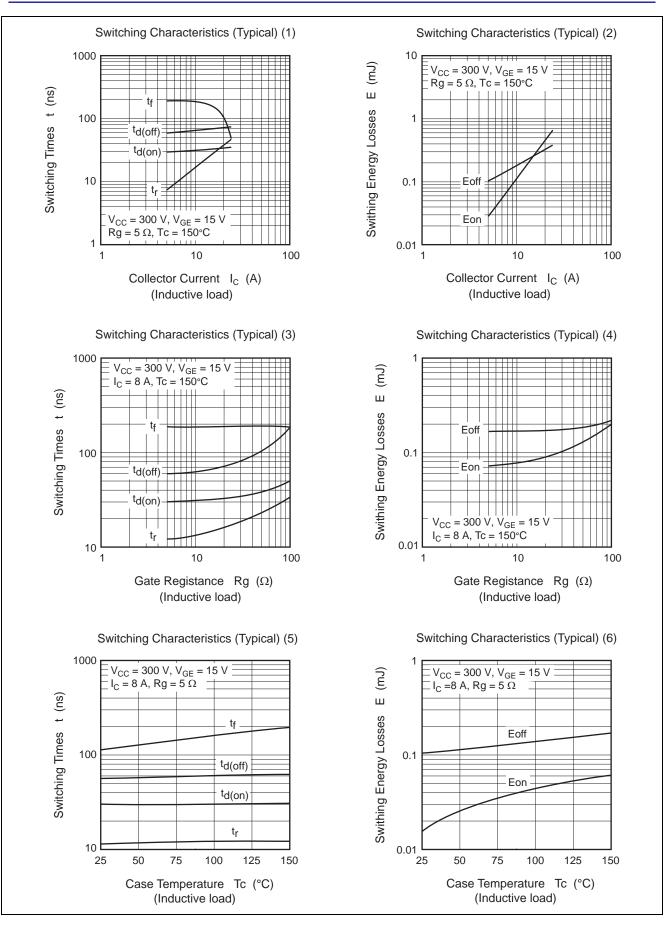


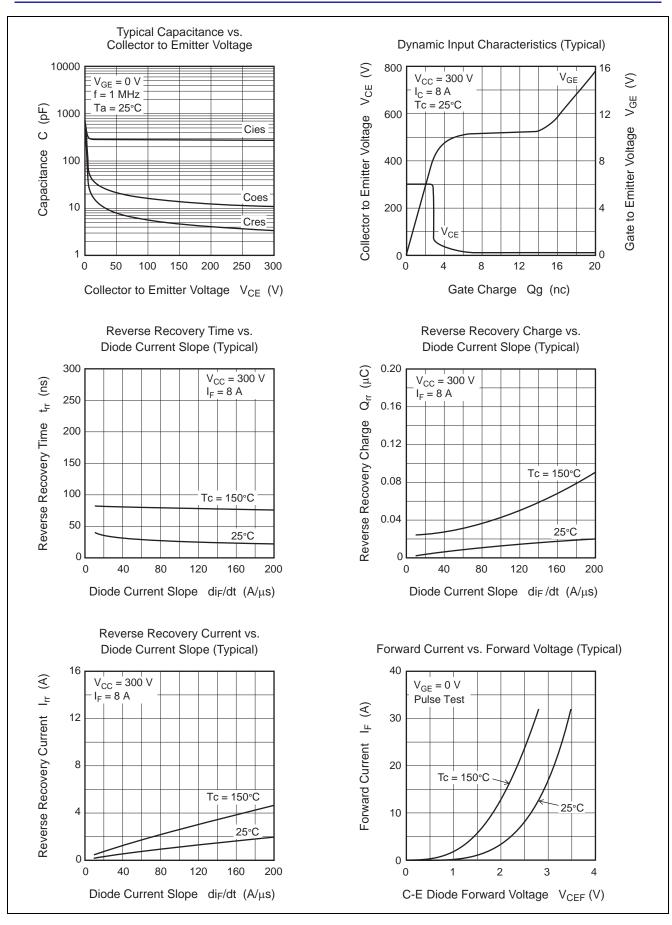
Main Characteristics

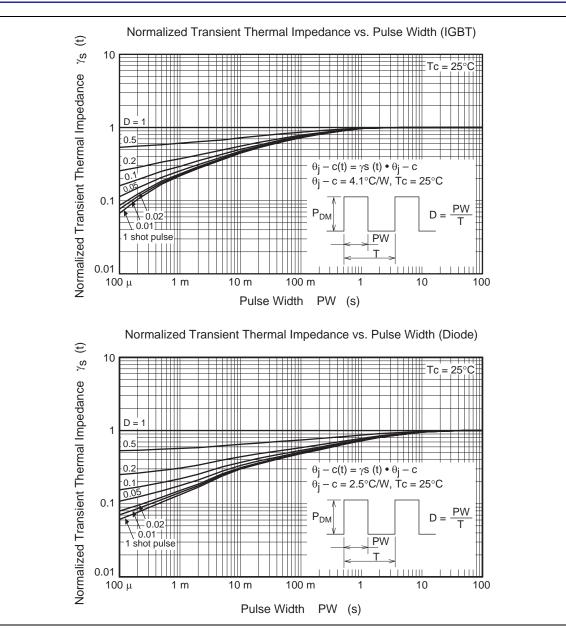




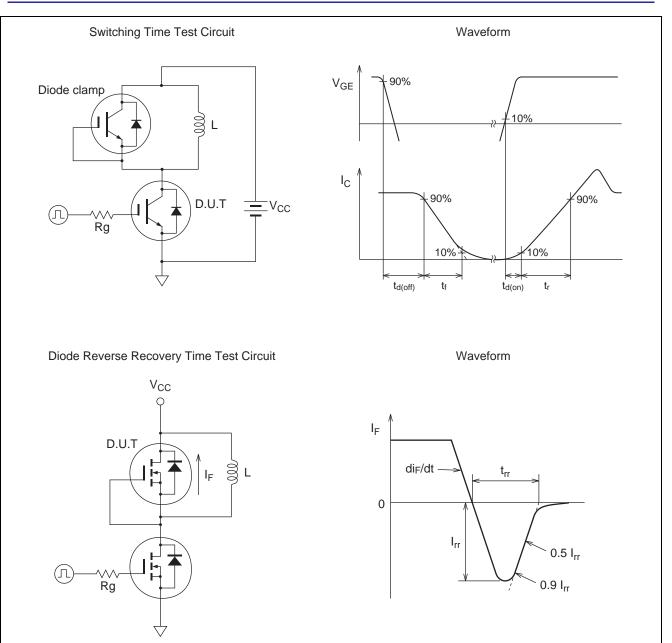






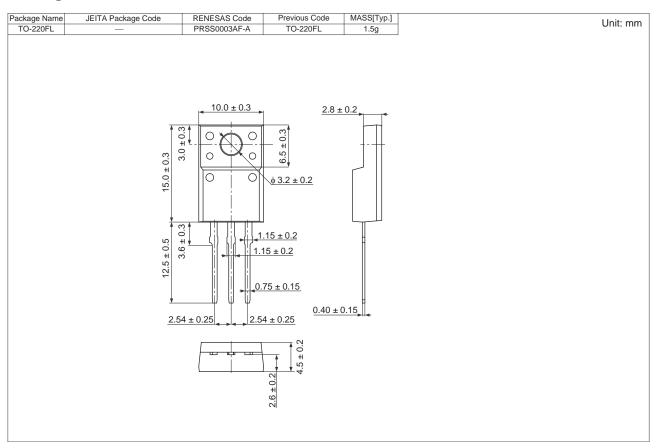








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH60V1BDPP-M0#T2	600 pcs	Box (Tube)



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